

HA17558B Series

Dual Operational Amplifier

REA03D0003-0100 Rev.1.00 Dec 25, 2006

Description

HA17558B is dual bipolar op-amp with improved characteristics compared to HA17558A. It has wide bandwidth, low noise, high slew rate; wide operating voltage range and high gain characteristics.

This product has a wide range of applications that is appropriate for audio application, as well as AC/DC converter.

Features

Wide bandwidth: 7 MHz
High speed: 3 V/μs

Low input noise voltage: 1 μVrms
 Large DC voltage gain: 110 dB

• Operating voltage: ±2 V to ±18 V

• Package outline available in Pb free lead frame:

DP-8

SOP-8 (JEITA) SOP-8 (JEDEC)

Applications

- Audio AC-3 decoder system
- Audio amplifier
- AC/DC converter

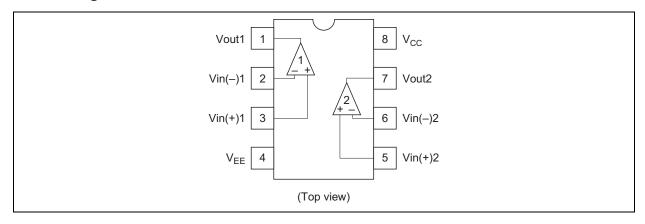
Ordering Information

Type No.	Application	Package Code (Package Name)
HA17558B	Commercial use	PRDP0008AF-B (DP-8FV)
HA17558BF		PRSP0008DE-B (FP-8DGV)
HA17558BRP		PRSP0008DD-C (FP-8DCV)

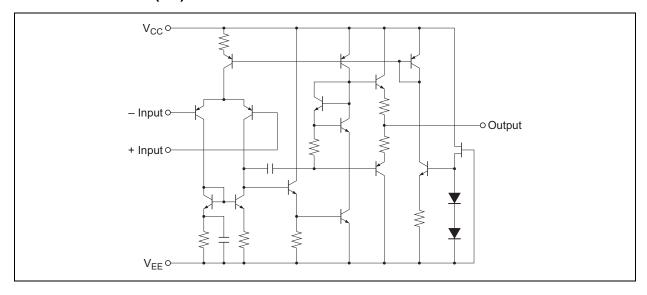
Note: This product is designed for consumer use and not for automotive.



Pin Arrangement



Circuit Schematic (1/2)



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

		Ratings			
Item	Symbol	HA17558B	HA17558BF	HA17558BRP	Unit
Supply Voltage	V _{CC}	18	18	18	V
	V _{EE}	-18	-18	-18	V
Differential input voltage	V _{IN} (diff)	±30	±30	±30	V
Common mode input voltage	V _{CM} * ³	±15	±15	±15	V
Power dissipation	P _T	670 * ¹	385 * ²	385 * ²	mW
Operating temperature	Topr	-40 to +85	-40 to +85	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	-55 to +125	-55 to +125	°C

Notes: 1. This is the allowable value up to Ta = 45°C. Derate by 8.3 mW/°C above that temperature.

- 2. These are the allowable values up to $Ta = 60^{\circ}C$ mounting on $40\text{mm} \times 40\text{mm} \times 1.6\text{mm}$ (t) 10% wiring density glass epoxy board. Derate by 5.9 mW/°C above that temperature.
- 3. If the supply voltage is less than ± 15 V, input voltage should be less than supply voltage.

Electrical Characteristics

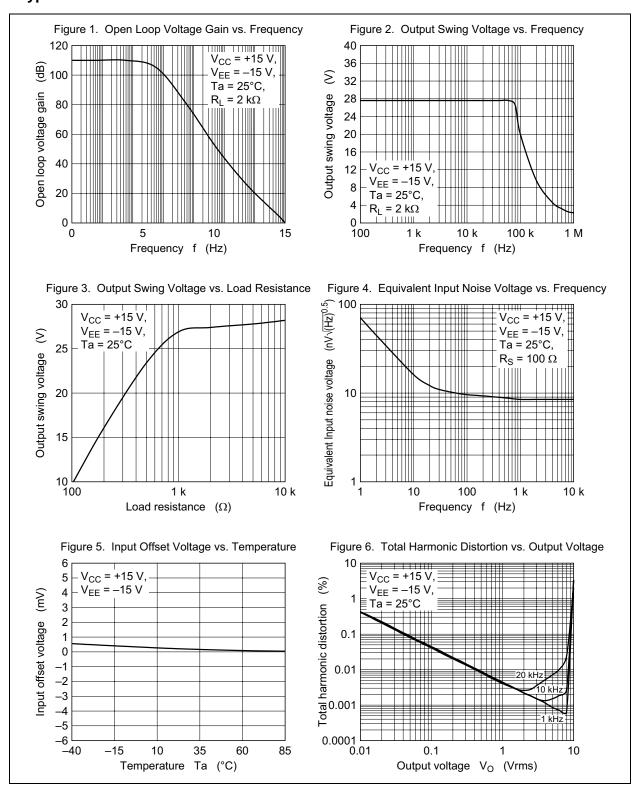
 $(Ta = 25^{\circ}C, V_{CC} = +15 \text{ V}, V_{EE} = -15 \text{ V}, \text{ unless otherwise specified})$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input offset voltage	V _{IO}	_	0.5	3	mV	$R_S \le 10 \text{ k}\Omega$
Input offset current	I _{IO}	_	5	50	nA	
Input bias current	I _{IB}		65	250	nA	
Supply current	Icc	_	2.5	4	mA	
Power supply rejection ratio	PSRR	80	100	_	dB	$R_S \le 10 \text{ k}\Omega$
Voltage gain	Av	85	110	_	dB	$R_L \ge 2~k\Omega,~V_O = \pm 10~V$
Common mode rejection ratio	CMR	80	100	_	dB	$R_S \le 10 \text{ k}\Omega$
Output swing voltage	Vos	±10	±13	_	V	$R_L \geq 2 \; k\Omega$
		±12	±14	_	V	$R_L \ge 10 \text{ k}\Omega$
Output sink current	I _{OSINK}	_	70	_	mA	$V_{IN(-)} = 1 \text{ V}, V_{IN(+)} = 0 \text{ V},$ $V_{O} = 2 \text{ V}$
Output source current	I _{OSOURCE}	_	45	_	mA	$V_{IN(-)} = 0 \text{ V}, V_{IN(+)} = 1 \text{ V},$ $V_{O} = 2 \text{ V}$
Slew rate	SR	_	3	_	V/μs	
Equivalent input noise voltage	V _{NI}	_	1	_	μVrms	RIAA, $R_S = 1 \text{ k}\Omega$, 30 kHz LPF
Gain bandwidth product	fu	_	7	_	MHz	f = 10 kHz
Total harmonic distortion	THD	_	0.0045	_	%	f = 1 kHz, V _O = 1 Vrms

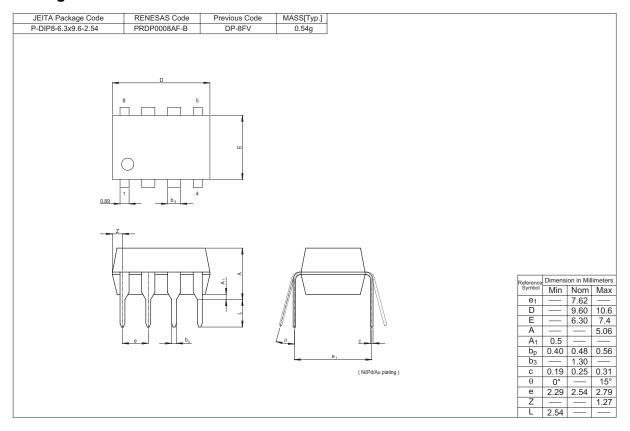
Table of Graphs

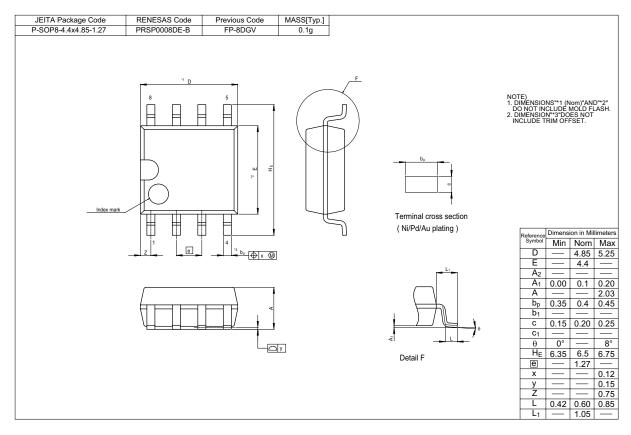
Electrical Characteristics		Figure	
Open loop voltage gain	vs. Frequency f	1	
Output swing voltage	vs. Frequency f	2	
Output swing voltage	vs. Load resistance R _L	3	
Equivalent input noise voltage	vs. Frequency f	4	
Input offset voltage	vs. Temperature Ta	5	
Total harmonic distortion	vs. Output Voltage Vo	6	

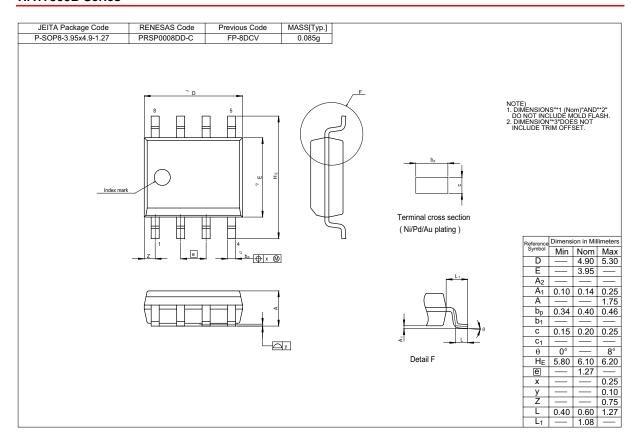
Typical Characteristics Curves



Package Dimensions







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